Silicon PIN diode

Rev. 5.1 — 8 February 2019

Product data sheet

1 Product profile

1.1 General description

General-purpose pin diode in an SOD323 small plastic SMD package.

1.2 Features and benefits

- · Low diode capacitance: maximum 1.05 pF
- Low diode forward resistance: max. 0.7 Ω
- AEC-Q101 qualified

1.3 Applications

· General RF applications

2 Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode		
2	anode	1 2	₩
		Top view	

3 Ordering information

Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
BAP51-03	-	plastic surface-mounted package; 2 leads	SOD323		

4 Marking

Table 3. Marking code

rabio or marking obac			
Type number	Marking code		
BAP51-03	A5 ^[1]		

[1] The marking bar indicates the cathode (see simplified outline graphic in <u>Table 1</u>).



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5 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	continuous reverse voltage		-	50	V
l _F	continuous forward current		-	50	mA
P _{tot}	total power dissipation	T _{sp} ≤ 90 °C	-	500	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6 Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point		120	K/W

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7 Characteristics

Table 6. Characteristics

 T_i = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V _F	forward voltage	I _F = 50 mA	-	0.95	1.1	V	
V _R	reverse voltage	I _R = 10 μA	50	-	-	V	
I _R	reverse current	V _R = 50 V	-	-	100	nA	
C _d	diode capacitance	f = 1 MHz (see <u>Figure 1</u>)					
		V _R = 0 V	-	0.4	-	pF	
		V _R = 1 V	-	0.3	0.55	pF	
		V _R = 5 V	-	0.2	0.35	pF	
r _D	diode forward resistance	f = 100 MHz (see <u>Figure 2</u>)					
		I _F = 0.5 mA	[1] -	5.5	9	Ω	
		I _F = 1 mA	[1] _	3.6	6.5	Ω	
		I _F = 10 mA	[1] _	1.5	2.5	Ω	
τι	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω ; measured at I_R = 3 mA	-	550	-	ns	

^[1] Guaranteed on AQL basis; inspection level S4, AQL 1.0

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8 Graphical data

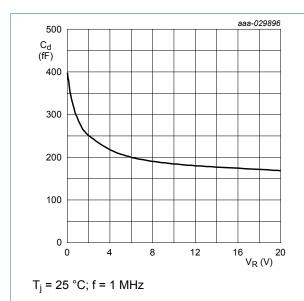
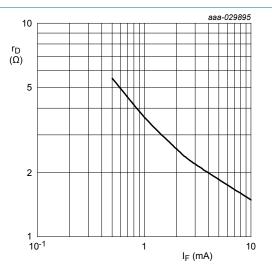
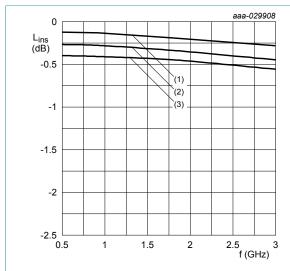


Figure 1. Diode capacitance as a function of reverse voltage (typical values)



 $T_i = 25 \,^{\circ}\text{C}$; f = 100 MHz.

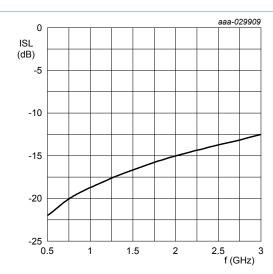
Figure 2. Diode forward resistance as a function of forward current (typical values)



Diode inserted in series with a 50 Ω strip line circuit and biased via the analyzer T-network; T_{amb} = 25 °C

- (1) $I_F = 10 \text{ mA}$
- (2) $I_F = 1 \text{ mA}$
- (3) $I_F = 0.5 \text{ mA}$

Figure 3. Insertion loss of the diode as a function of frequency (typical values)



Diode zero-biased and inserted in series with a 50 Ω strip line circuit and biased via the analyzer T-network; T_{amb} = 25 °C; f = 100 MHz

Figure 4. Isolation of the diode as a function of frequency (typical values)

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9 Package outline

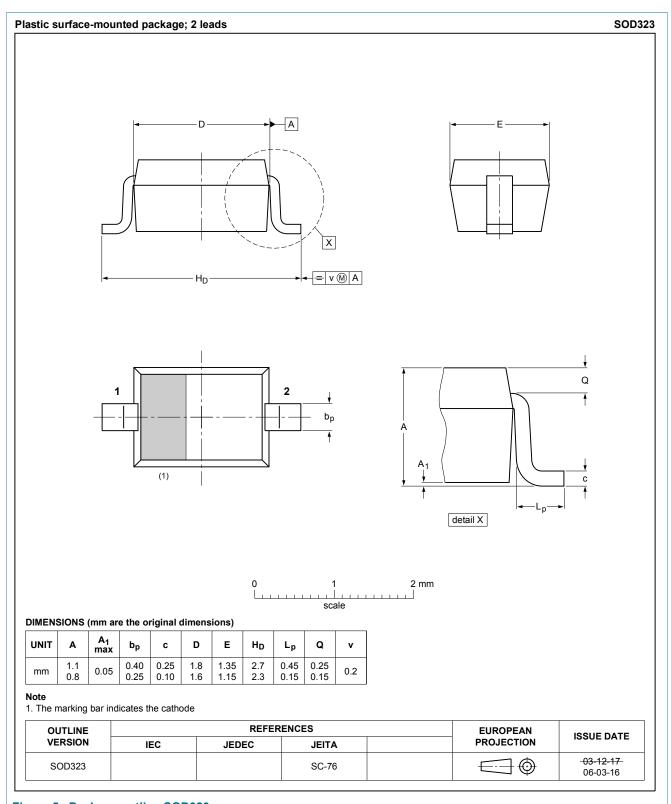


Figure 5. Package outline SOD323

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10 Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP51-03 v.5.1	20190208	Product data sheet	-	BAP51-03 v.5
Modifications:	aligned the title or	f the data sheet with the	description on the li	nternet
BAP51-03 v.5	20181126	Product data sheet	-	BAP51-03 v.3.1
Modifications:	 AEC-Q101 qualification added to the features and benefits Section 1.2 "Features and benefits" has been updated. The "Legal information" pages have been updated to automotive version 			
BAP51-03 v.4.1	20040211	Product data sheet	-	-

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11 Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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